

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VCX162835FT

## Low-Voltage 18-Bit Universal Bus Driver with 3.6-V Tolerant Inputs and Outputs

The TC74VCX162835FT is a high-performance CMOS 18-bit universal bus driver. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

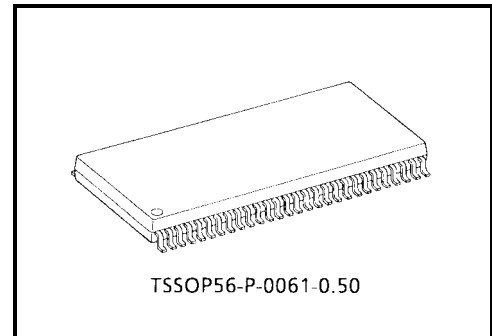
It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

Data flow from A to Y is controlled by the output-enable ( $\overline{OE}$ ) input.

The device operates in the transparent mode when the latch-enable (LE) input is high. When LE is low, the A data is latched if the clock (CK) input is held at a high or low logic level. If LE is low, the A data is stored in the latch/flip-flop on the low-to-high transition of CK.

When  $\overline{OE}$  is high, the outputs are in a high-impedance state. The 26- $\Omega$  series resistor helps reducing output overshoot and undershoot without external resistor.

All inputs are equipped with protection circuits against static discharge.

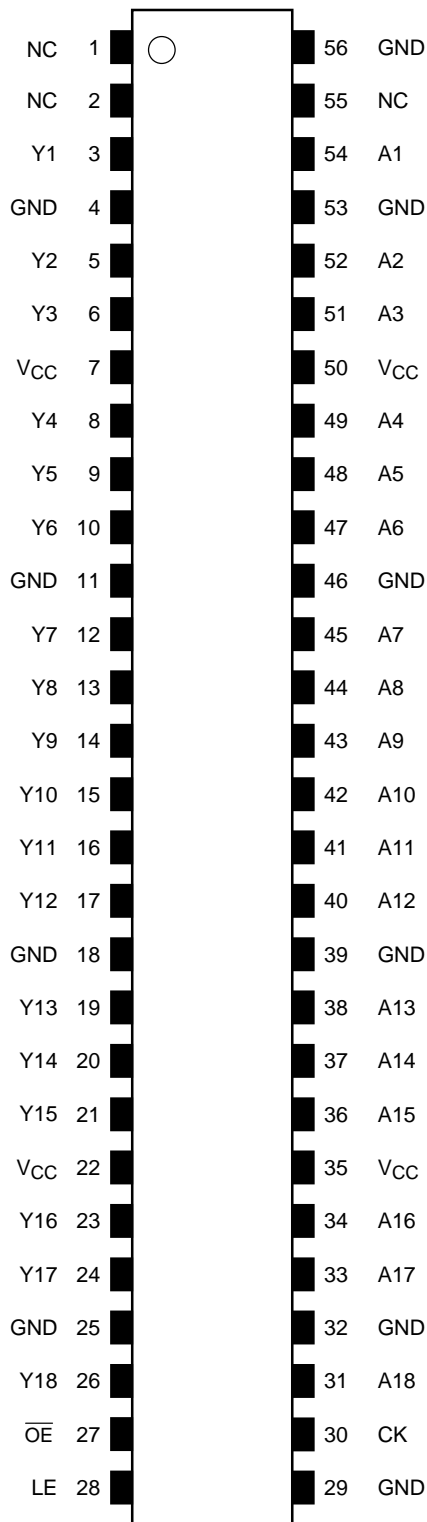


Weight: 0.25 g (typ.)

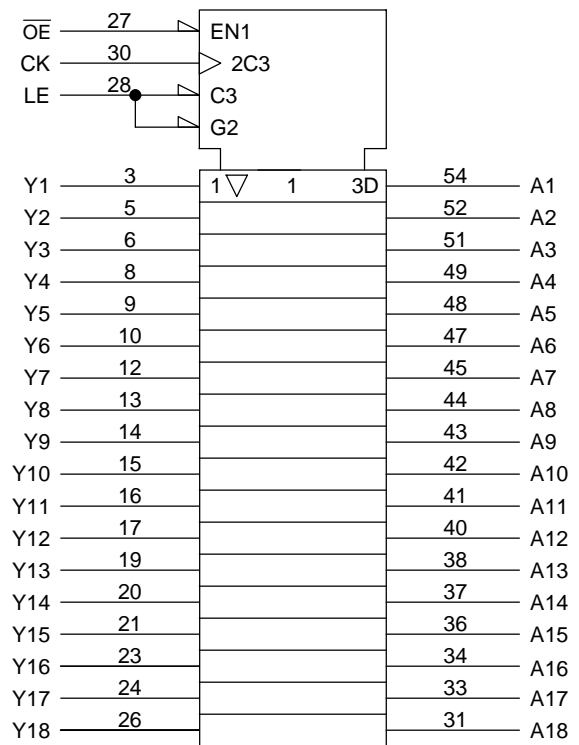
### Features

- 26- $\Omega$  series resistors on outputs
- Low-voltage operation:  $V_{CC} = 1.8$  to 3.6 V
- High-speed operation:  $t_{pd} = 3.9$  ns (max) ( $V_{CC} = 3.0$  to 3.6 V)  
     :  $t_{pd} = 5.0$  ns (max) ( $V_{CC} = 2.3$  to 2.7 V)  
     :  $t_{pd} = 9.8$  ns (max) ( $V_{CC} = 1.8$  V)
- Output current:  $I_{OH}/I_{OL} = \pm 12$  mA (min) ( $V_{CC} = 3.0$  V)  
     :  $I_{OH}/I_{OL} = \pm 8$  mA (min) ( $V_{CC} = 2.3$  V)  
     :  $I_{OH}/I_{OL} = \pm 4$  mA (min) ( $V_{CC} = 1.8$  V)
- Latch-up performance:  $\pm 300$  mA
- ESD performance: Machine model  $> \pm 200$  V  
     : Human body model  $> \pm 2000$  V
- Package: TSSOP (thin shrink small outline package)
- 3.6-V tolerant function and power-down protection provided on all inputs and outputs

## Pin Assignment (top view)



## IEC Logic Symbol



**Truth Table**

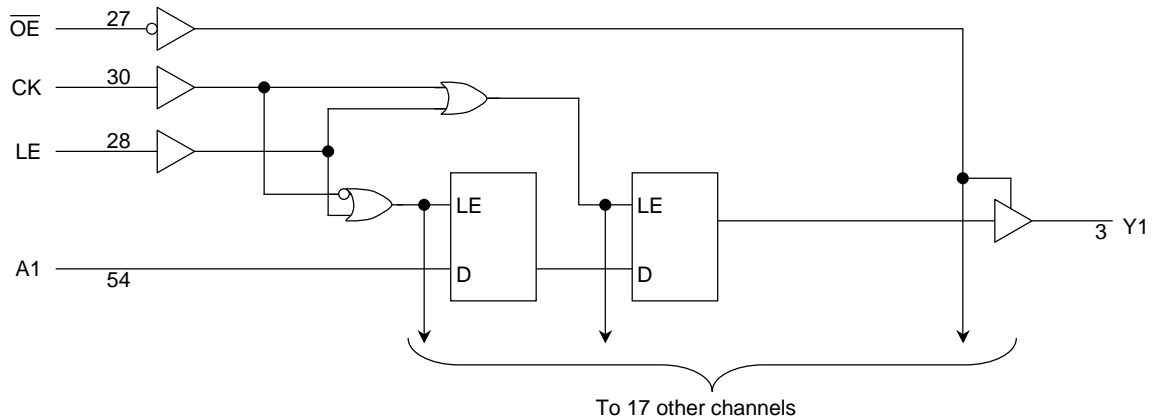
Inputs				Outputs
$\overline{OE}$	LE	CK	A	Y
H	X	X	X	Z
L	H	X	L	L
L	H	X	H	H
L	L	$\uparrow$	L	L
L	L	$\uparrow$	H	H
L	L	H	X	Y0 (Note 1)
L	L	L	X	Y0 (Note 1)

X: Don't care

Z: High impedance

Note 1: Output level before the indicated steady-state input conditions were established, provided that CK was high or low before LE went low.

**System Diagram**



## Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	$V_{CC}$	-0.5 to 4.6	V
DC input voltage	$V_{IN}$	-0.5 to 4.6	V
DC output voltage	$V_{OUT}$	-0.5 to 4.6 (Note 2)	V
		-0.5 to $V_{CC} + 0.5$ (Note 3)	
Input diode current	$I_{IK}$	-50	mA
Output diode current	$I_{OK}$	$\pm 50$ (Note 4)	mA
DC output current	$I_{OUT}$	$\pm 50$	mA
Power dissipation	$P_D$	400	mW
DC $V_{CC}$ /ground current per supply pin	$I_{CC}/I_{GND}$	$\pm 100$	mA
Storage temperature	$T_{stg}$	-65 to 150	$^{\circ}C$

Note 2: OFF state

Note 3: High or low state.  $I_{OUT}$  absolute maximum rating must be observed.

Note 4:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$

## Recommended Operating Range

Characteristics	Symbol	Rating	Unit
Power supply voltage	$V_{CC}$	1.8 to 3.6	V
		1.2 to 3.6 (Note 5)	
Input voltage	$V_{IN}$	-0.3 to 3.6	V
Output voltage	$V_{OUT}$	0 to 3.6 (Note 6)	V
		0 to $V_{CC}$ (Note 7)	
Output current	$I_{OH}/I_{OL}$	$\pm 12$ (Note 8)	mA
		$\pm 8$ (Note 9)	
		$\pm 4$ (Note 10)	
Operating temperature	$T_{opr}$	-40 to 85	$^{\circ}C$
Input rise and fall time	dt/dv	0 to 10 (Note 11)	ns/V

Note 5: Data retention only

Note 6: OFF state

Note 7: High or low state

Note 8:  $V_{CC} = 3.0$  to  $3.6$  V

Note 9:  $V_{CC} = 2.3$  to  $2.7$  V

Note 10:  $V_{CC} = 1.8$  V

Note 11:  $V_{IN} = 0.8$  to  $2.0$  V,  $V_{CC} = 3.0$  V

**Electrical Characteristics**

**DC Characteristics (Ta = -40 to 85°C, 2.7 V < VCC ≤ 3.6 V)**

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>	—		2.7 to 3.6	2.0	—	V
	L-level	V <sub>IL</sub>	—		2.7 to 3.6	—	0.8	
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	2.7 to 3.6	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -6 mA	2.7	2.2	—	
				I <sub>OH</sub> = -8 mA	3.0	2.4	—	
				I <sub>OH</sub> = -12 mA	3.0	2.2	—	
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.7 to 3.6	—	0.2	
				I <sub>OL</sub> = 6 mA	2.7	—	0.4	
				I <sub>OL</sub> = 8 mA	3.0	—	0.55	
				I <sub>OL</sub> = 12 mA	3.0	—	0.8	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		2.7 to 3.6	—	±5.0	μA
3-state output OFF state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 3.6 V		2.7 to 3.6	—	±10.0	μA
Power-off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7 to 3.6	—	20.0	μA
			V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V		2.7 to 3.6	—	±20.0	
Increase in I <sub>CC</sub> per input		ΔI <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V		2.7 to 3.6	—	750	

**DC Characteristics (Ta = -40 to 85°C, 2.3 V ≤ VCC ≤ 2.7 V)**

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>	—		2.3 to 2.7	1.6	—	V
	L-level	V <sub>IL</sub>	—		2.3 to 2.7	—	0.7	
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	2.3 to 2.7	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -4 mA	2.3	2.0	—	
				I <sub>OH</sub> = -6 mA	2.3	1.8	—	
				I <sub>OH</sub> = -8 mA	2.3	1.7	—	
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.3 to 2.7	—	0.2	
				I <sub>OL</sub> = 6 mA	2.3	—	0.4	
				I <sub>OL</sub> = 8 mA	2.3	—	0.6	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		2.3 to 2.7	—	±5.0	μA
3-state output OFF state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 3.6 V		2.3 to 2.7	—	±10.0	μA
Power-off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.3 to 2.7	—	20.0	μA
			V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V		2.3 to 2.7	—	±20.0	

## DC Characteristics (Ta = -40 to 85°C, 1.8 V ≤ VCC < 2.3 V)

Characteristics		Symbol	Test Condition		VCC (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>	—		1.8 to 2.3	0.7 × V <sub>CC</sub>	—	V
	L-level	V <sub>IL</sub>	—		1.8 to 2.3	—	0.2 × V <sub>CC</sub>	
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	1.8	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -4 mA	1.8	1.4	—	
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	1.8	—	0.2	
				I <sub>OL</sub> = 4 mA	1.8	—	0.3	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		1.8	—	±5.0	μA
3-state output OFF state current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 3.6 V		1.8	—	±10.0	μA
Power-off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		1.8	—	20.0	μA
			V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V		1.8	—	±20.0	

## AC Characteristics (Ta = -40 to 85°C, input: tr = tf = 2.0 ns, CL = 30 pF, RL = 500 Ω)

Characteristics	Symbol	Test Condition	VCC (V)	Min	Max	Unit
Maximum clock frequency	f <sub>max</sub>	Figure 1, Figure 3	1.8	100	—	MHz
			2.5 ± 0.2	200	—	
			3.3 ± 0.3	250	—	
Propagation delay time (An-Yn)	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 2	1.8	1.5	9.8	ns
			2.5 ± 0.2	0.8	5.0	
			3.3 ± 0.3	0.6	3.9	
Propagation delay time (CK-Yn)	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 3	1.8	2.0	9.2	ns
			2.5 ± 0.2	1.5	5.2	
			3.3 ± 0.3	1.4	4.2	
Propagation delay time (LE-Yn)	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 4	1.8	1.5	9.8	ns
			2.5 ± 0.2	0.8	5.8	
			3.3 ± 0.3	0.6	4.7	
Output enable time	t <sub>pZL</sub> t <sub>pZH</sub>	Figure 1, Figure 5	1.8	1.5	9.8	ns
			2.5 ± 0.2	0.8	5.9	
			3.3 ± 0.3	0.6	4.3	
Output disable time	t <sub>pLZ</sub> t <sub>pHZ</sub>	Figure 1, Figure 5	1.8	1.5	7.9	ns
			2.5 ± 0.2	0.8	4.7	
			3.3 ± 0.3	0.6	4.2	
Minimum pulse width	t <sub>W</sub> (H) t <sub>W</sub> (L)	Figure 1, Figure 3, Figure 4	1.8	4.0	—	ns
			2.5 ± 0.2	1.5	—	
			3.3 ± 0.3	1.5	—	
Minimum setup time (An-CK, An-LE)	t <sub>s</sub>	Figure 1, Figure 3, Figure 4	1.8	2.5	—	ns
			2.5 ± 0.2	1.5	—	
			3.3 ± 0.3	1.5	—	
Minimum hold time (An-CK, An-LE)	t <sub>h</sub>	Figure 1, Figure 3, Figure 4	1.8	1.0	—	ns
			2.5 ± 0.2	0.7	—	
			3.3 ± 0.3	0.7	—	
Output to output skew	t <sub>osLH</sub> t <sub>osHL</sub>	(Note 12)	1.8	—	0.5	ns
			2.5 ± 0.2	—	0.5	
			3.3 ± 0.3	—	0.5	

Note 12: Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

**AC Characteristics (Ta = 0 to 85°C, input: tr = tf = 2.0 ns, CL = 0 pF, RL = 500 Ω)**

Characteristics	Symbol	Test Condition	VCC (V)	Min	Max	Unit
Propagation delay time (An-Yn)	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 2 (Note 13)	3.3 ± 0.15	0.9	2.0	ns
Propagation delay time (CK-Yn)	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 3 (Note 13)	3.3 ± 0.15	1.4	2.9	ns
Propagation delay time (LE-Yn)	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 4 (Note 13)	3.3 ± 0.15	0.7	3.4	ns
Output enable time	t <sub>pZL</sub> t <sub>pZH</sub>	Figure 1, Figure 5 (Note 13)	3.3 ± 0.15	0.7	3.0	ns
Output disable time	t <sub>pLZ</sub> t <sub>pHZ</sub>	Figure 1, Figure 5 (Note 13)	3.3 ± 0.15	0.7	2.9	ns
Minimum set-up time (An-CK, An-LE)	t <sub>s</sub>	Figure 1, Figure 3, Figure 4 (Note 13)	3.3 ± 0.15	1.5	—	ns
Minimum hold time (An-CK, An-LE)	t <sub>h</sub>	Figure 1, Figure 3, Figure 4 (Note 13)	3.3 ± 0.15	0.7	—	ns

Note 13: TOSHIBA SPICE simulation data.

**AC Characteristics (Ta = 0 to 85°C, input: tr = tf = 2.0 ns, CL = 50 pF, RL = 500 Ω)**

Characteristics	Symbol	Test Condition	VCC (V)	Min	Max	Unit
Propagation delay time (An-Yn)	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 2	3.3 ± 0.15	1.0	4.2	ns
Propagation delay time (CK-Yn)	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 3	3.3 ± 0.15	1.9	4.5	ns
Propagation delay time (LE-Yn)	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 4	3.3 ± 0.15	1.0	5.0	ns
Output enable time	t <sub>pZL</sub> t <sub>pZH</sub>	Figure 1, Figure 5	3.3 ± 0.15	1.0	4.6	ns
Output disable time	t <sub>pLZ</sub> t <sub>pHZ</sub>	Figure 1, Figure 5	3.3 ± 0.15	1.0	4.5	ns
Minimum setup time (An-CK, An-LE)	t <sub>s</sub>	Figure 1, Figure 3, Figure 4	3.3 ± 0.15	1.5	—	ns
Minimum hold time (An-CK, An-LE)	t <sub>h</sub>	Figure 1, Figure 3, Figure 4	3.3 ± 0.15	0.7	—	ns



**Dynamic Switching Characteristics**

(Ta = 25°C, input: tr = tf = 2.0 ns, CL = 30 pF, RL = 500 Ω)

Characteristics	Symbol	Test Condition		Typ.	Unit	
			VCC (V)			
Quiet output maximum dynamic VOL	VOLP	VIH = 1.8 V, VIL = 0 V	(Note 14)	1.8	0.25	V
		VIH = 2.5 V, VIL = 0 V	(Note 14)	2.5	0.35	
		VIH = 3.3 V, VIL = 0 V	(Note 14)	3.3	0.45	
Quiet output minimum dynamic VOL	VOLV	VIH = 1.8 V, VIL = 0 V	(Note 14)	1.8	-0.25	V
		VIH = 2.5 V, VIL = 0 V	(Note 14)	2.5	-0.35	
		VIH = 3.3 V, VIL = 0 V	(Note 14)	3.3	-0.45	
Quiet output minimum dynamic VOH	VOHV	VIH = 1.8 V, VIL = 0 V	(Note 14)	1.8	1.35	V
		VIH = 2.5 V, VIL = 0 V	(Note 14)	2.5	1.85	
		VIH = 3.3 V, VIL = 0 V	(Note 14)	3.3	2.45	

Note 14: Parameter guaranteed by design.

**Capacitive Characteristics (Ta = 25°C)**

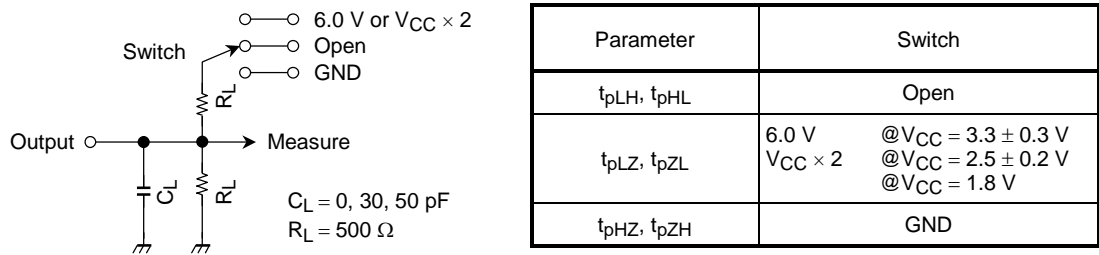
Characteristics	Symbol	Test Condition		Typ.	Unit	
			VCC (V)			
Input capacitance	CIN	—		1.8, 2.5, 3.3	6	pF
Output capacitance	COU	—		1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	CPD	fIN = 10 MHz	(Note 15)	1.8, 2.5, 3.3	20	pF

Note 15: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

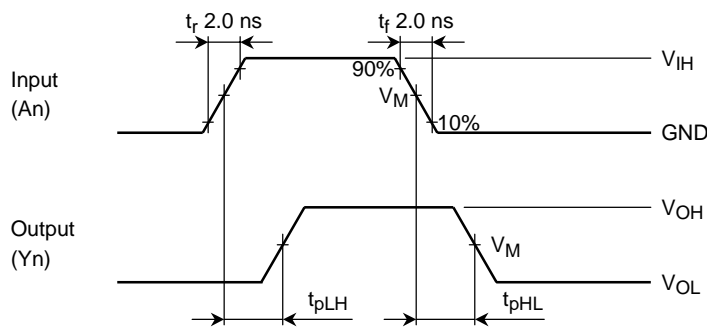
$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/18 \text{ (per bit)}$$

**AC Test Circuit**

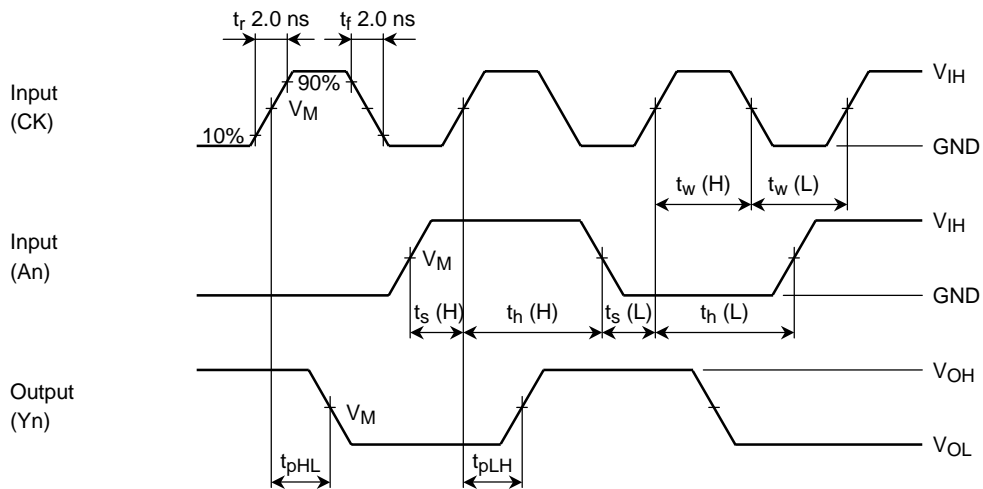


**Figure 1**

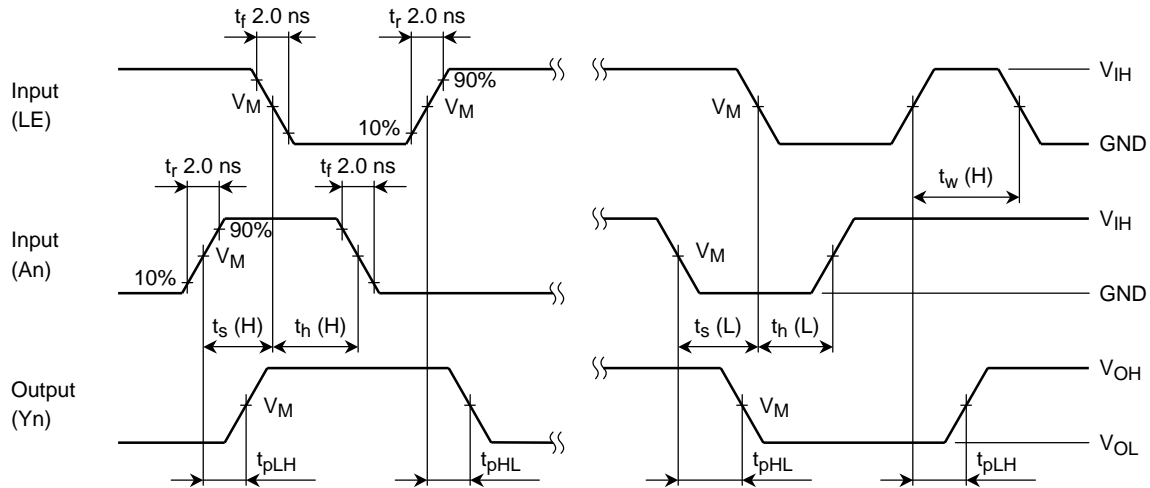
**AC Waveform**



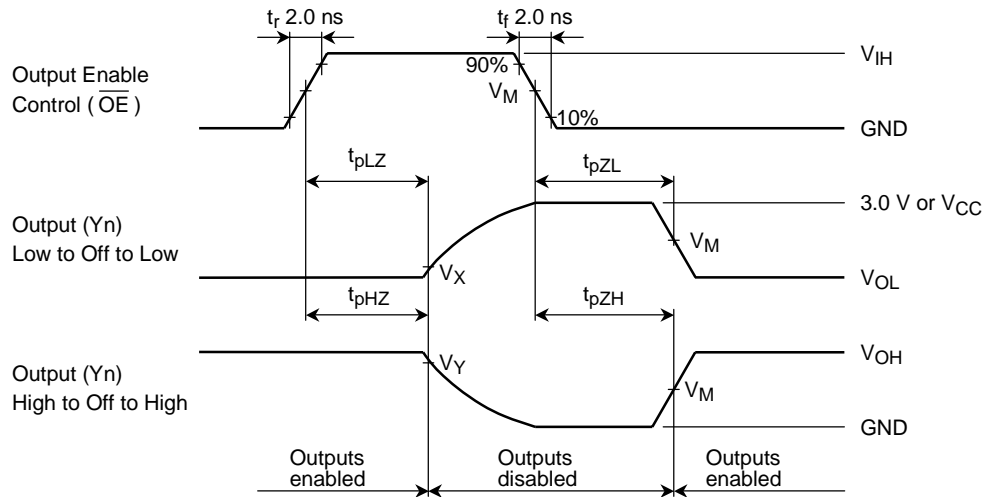
**Figure 2  $t_{pLH}$ ,  $t_{pHL}$**



**Figure 3  $t_{pLH}$ ,  $t_{pHL}$ ,  $t_w$ ,  $t_s$ ,  $t_h$**



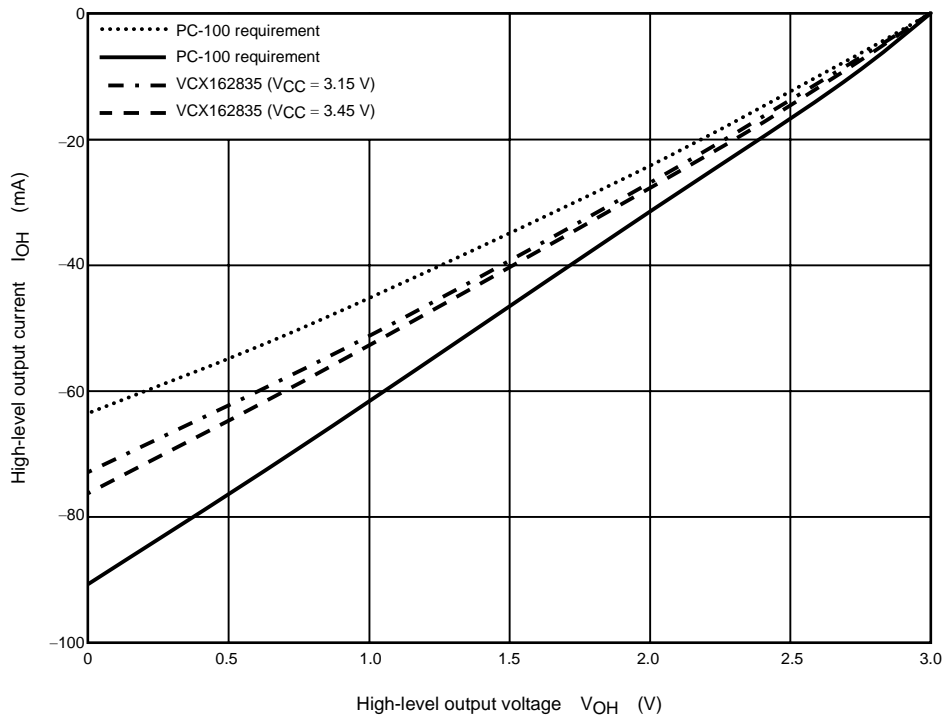
**Figure 4**  $t_{pLH}$ ,  $t_{pHL}$ ,  $t_w$ ,  $t_s$ ,  $t_h$



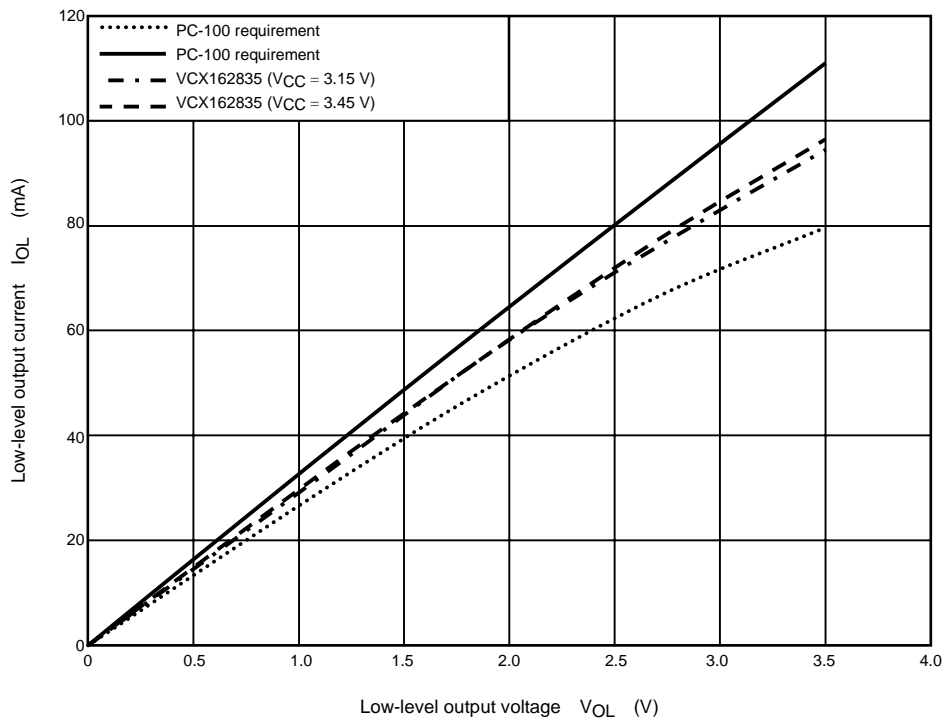
**Figure 5**  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$

Symbol	$V_{CC}$		
	$3.3 \pm 0.3 \text{ V}$	$2.5 \pm 0.2 \text{ V}$	$1.8 \text{ V}$
$V_{IH}$	$2.7 \text{ V}$	$V_{CC}$	$V_{CC}$
$V_M$	$1.5 \text{ V}$	$V_{CC}/2$	$V_{CC}/2$
$V_X$	$V_{OL} + 0.3 \text{ V}$	$V_{OL} + 0.15 \text{ V}$	$V_{OL} + 0.15 \text{ V}$
$V_Y$	$V_{OH} - 0.3 \text{ V}$	$V_{OH} - 0.15 \text{ V}$	$V_{OH} - 0.15 \text{ V}$

**IBIS Characteristics (typ.)**



**Figure 6 I/V characteristics vs. pull-up**

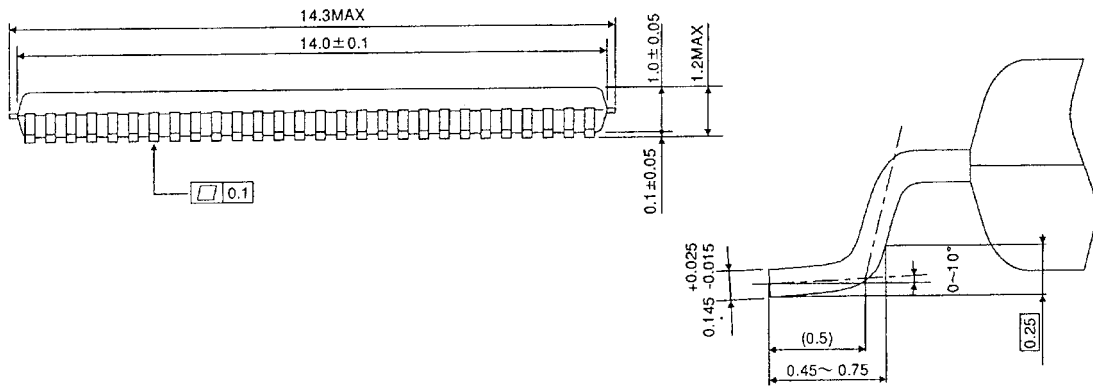
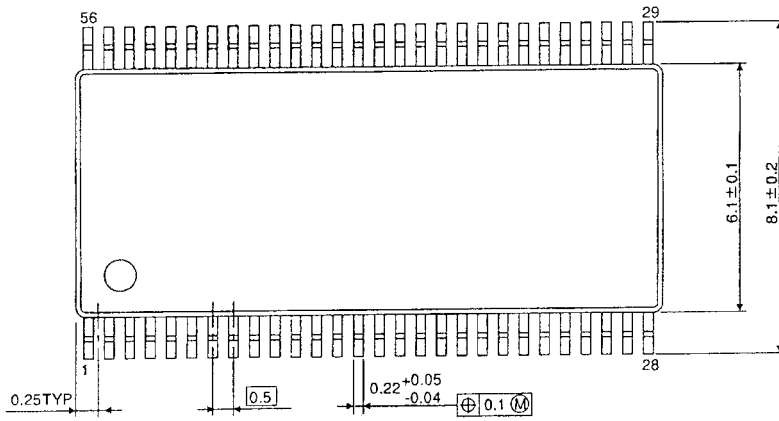


**Figure 7 I/V characteristics vs. pull-down**

**Package Dimensions**

TSSOP56-P-0061-0.50

Unit : mm



Weight: 0.25 g (typ.)

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000707EBA

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